Product data sheet

1. General description

Ultrafast power diode in a SOT404 (D2PAK) surface-mountable plastic package.

2. Features and benefits

- Fast switching
- High thermal cycling performance
- Low forward volt drop
- · Low thermal resistance
- · Soft recovery minimizes power-consuming oscillations
- Surface mountable package

3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- · Output rectifiers in high-frequency switched-mode power supplies

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_R	reverse voltage	DC	-	-	500	V
I _{F(AV)}	average forward current	$\delta = 0.5$; $T_{mb} \le 123$ °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	-	9	A
I _{FRM}	repetitive peak forward current	$\delta = 0.5 \; ; t_p = 25 \; \mu s; T_{mb} \le \; 123 \; ^{\circ}C;$ SQW	-	-	18	A
I _{FSM}	non-repetitive peak forward current	t _p = 10 ms; T _{j(init)} = 25 °C; SIN	-	-	100	Α
		t _p = 8.3 ms; T _{j(init)} = 25 °C; SIN	-	-	110	Α
Static characte	eristics					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.9	1.03	V
		I _F = 8 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.05	1.25	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.2	1.4	V
Dynamic chara	acteristics			•	•	
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/s};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 5}}; \underline{\text{Fig. 6}}$	-	50	60	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	no connection	mb	K — A
2	K	cathode[1]		001aaa020
3	Α	anode		
mb	K	mounting base; cathode	D2PAK (SOT404)	

[1] it is not possible to make a connection to Pin 2 of the SOT404 package

6. Ordering information

Table 3. Ordering information

Type number	Package				
	Name	Description	Version		
BYV29B-500	D2PAK	plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped)	SOT404		

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{RRM}	repetitive peak reverse voltage		-	500	V
V_{RWM}	crest working reverse voltage		-	500	V
V_R	reverse voltage	DC	-	500	V
I _{F(AV)}	average forward current	δ = 0.5 ; T _{mb} \leq 123 °C; SQW; <u>Fig. 1</u> ; <u>Fig. 2</u>	-	9	A
I _{FRM}	repetitive peak forward current	$\delta = 0.5 \; ; t_p = 25 \; \mu s; T_{mb} \le 123 \; ^{\circ}C; \; SQW$	-	18	А
I _{FSM}	non-repetitive peak	t_p = 10 ms; $T_{j(init)}$ = 25 °C; SIN	-	100	Α
	forward current	t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; SIN	-	110	Α
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C

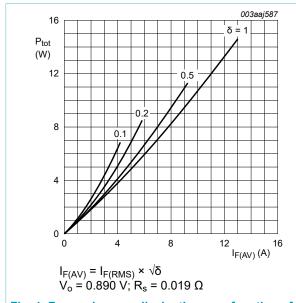


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values

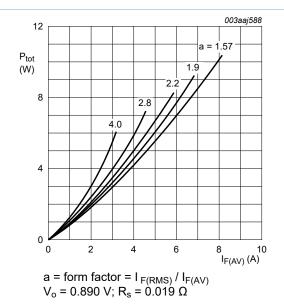


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 3		-	-	2.5	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	[1]	-	50	-	K/W

[1] Device mounted on a FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

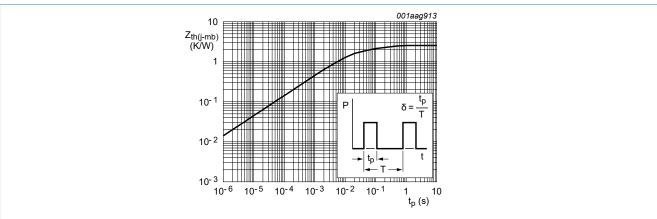
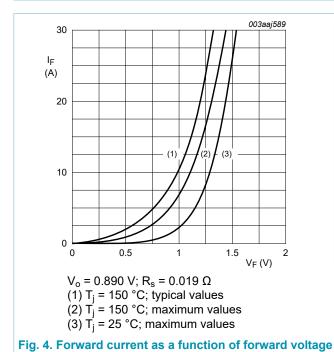


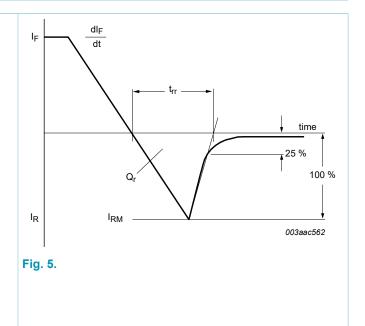
Fig. 3. Transient thermal impedance from junction to mounting base as a function of pulse width

9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
V _F	forward voltage	I _F = 8 A; T _j = 150 °C; <u>Fig. 4</u>	-	0.9	1.03	V
		I _F = 8 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.05	1.25	V
		I _F = 20 A; T _j = 25 °C; <u>Fig. 4</u>	-	1.2	1.4	V
I _R	reverse current	V _R = 500 V; T _j = 25 °C	-	2	50	μA
		V _R = 500 V; T _j = 100 °C	-	0.1	0.35	mA
Dynamic ch	naracteristics					
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/s}$; $T_j = 25 \text{ °C}$; Fig. 5; Fig. 6	-	50	60	ns
I _{RM}	peak reverse recovery current	$I_F = 10 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 50 \text{ A/s}$; $T_j = 100 \text{ °C}$; $\overline{\text{Fig. 5}}$; $\overline{\text{Fig. 7}}$	-	4	5.5	Α
Q _r	recovered charge	I _F = 2 A; V _R = 30 V; dI _F /dt = 20 A/s; T _j = 25 °C; <u>Fig. 8</u> ; <u>Fig. 5</u>	-	40	60	nC
V_{FR}	forward recovery voltage	$I_F = 10 \text{ A}; dI_F/dt = 10 \text{ A/s}; T_j = 25 °C;$ Fig. 9	-	2.5	-	V





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Ultrafast power diode

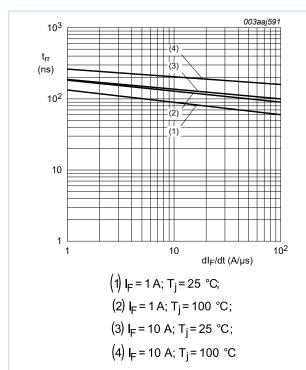


Fig. 6. Reverse recovery time as a function of rate of change of forward current; maximum values

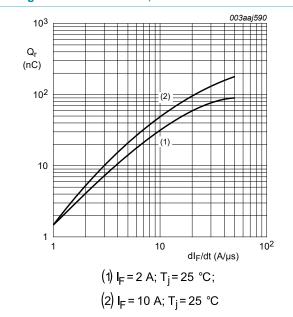


Fig. 8. Recovered charge as a function of rate of change of forward current; maximum values

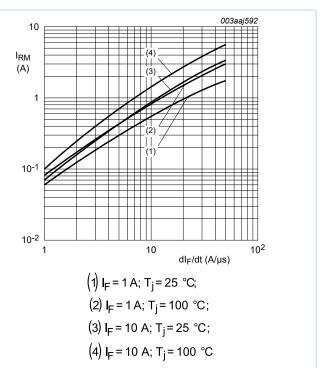


Fig. 7. Peak reverse recovery current as a function of rate of change of forward current; maximum values

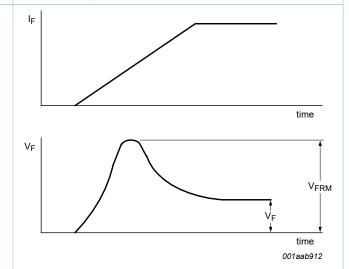
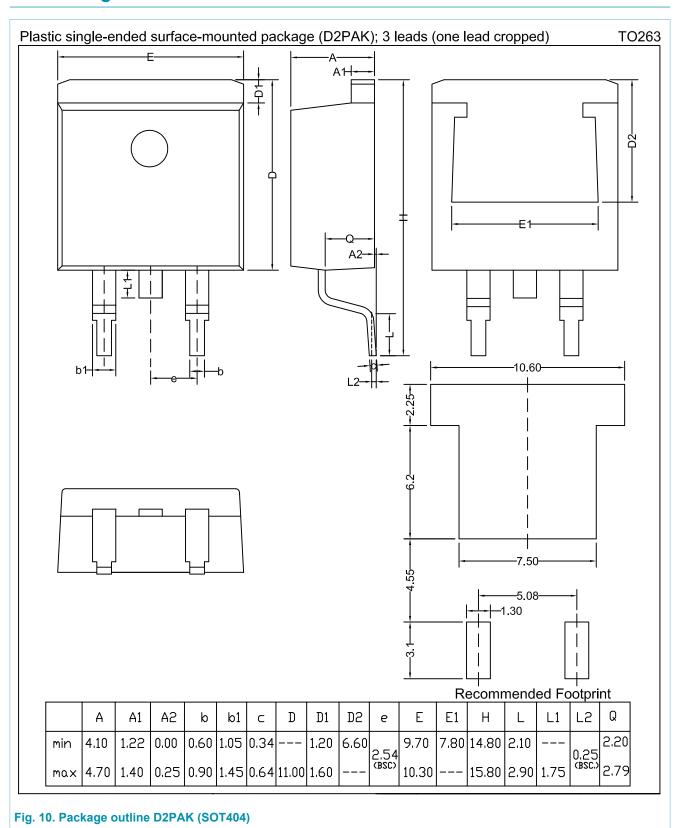


Fig. 9. Forward recovery definitions

10. Package outline



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Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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12. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Limiting values	3
8.	Thermal characteristics	4
9.	Characteristics	5
10.	Package outline	7
11.	Legal information	E

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